

MG031L080006A

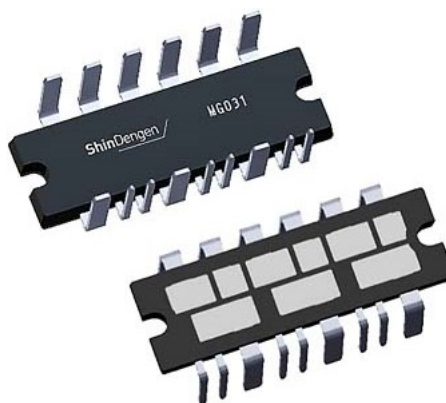
3 phase Inverter Module

Feature

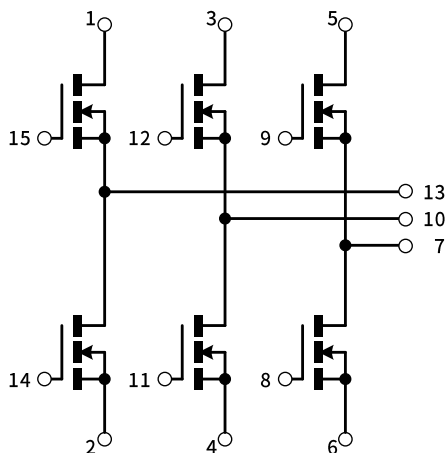
- 3 phase Inverter
- MOSFET(N-channel)
- High current capacity
- Low Ron
- Halogen free
- Pb free terminal
- RoHS:Yes

Outline

House Name: MG031



Equivalent circuit



Absolute maximum ratings (Tc = 25°C unless otherwise specified)

MOSFET

Item	Symbol	Conditions	Ratings	Unit
Channel temperature	Tch		175	°C
Drain-source voltage	V _{DSS}		60	V
Gate-source voltage	V _{GSS}		±20	V
Continuous drain current (DC)	I _D		80	A
Continuous drain current (Peak)	I _{DP}	Pulse width 10μs, Duty = 1/100	320	A
Total power dissipation	P _T		125	W
Single avalanche current	I _{AS}	Starting Tch=25°C Tch ≤ 150°C	31	A
Single avalanche energy	E _{AS}	Starting Tch=25°C Tch ≤ 150°C	116	mJ

Module

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55~150	°C
Mounting torque	TOR	Fixing screw M3	0.8	N · m

These are characteristics of the 1 chip unless otherwise specified.

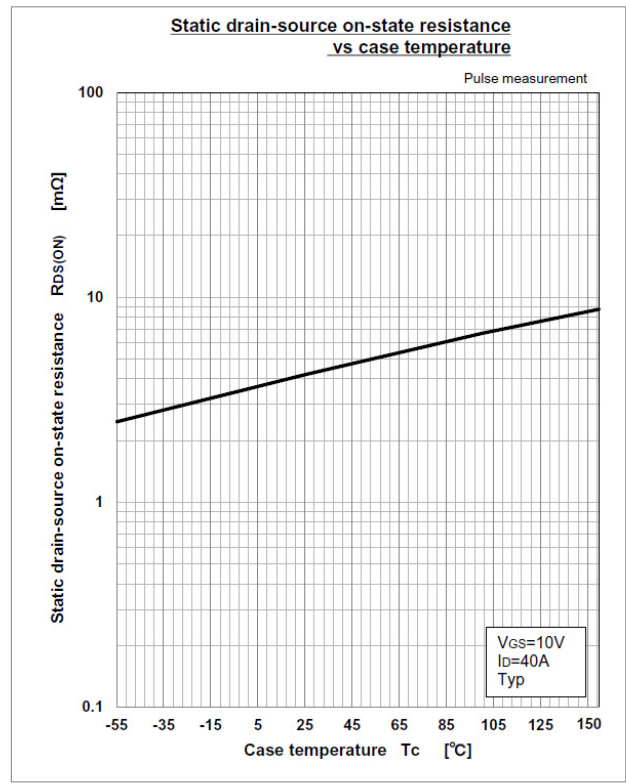
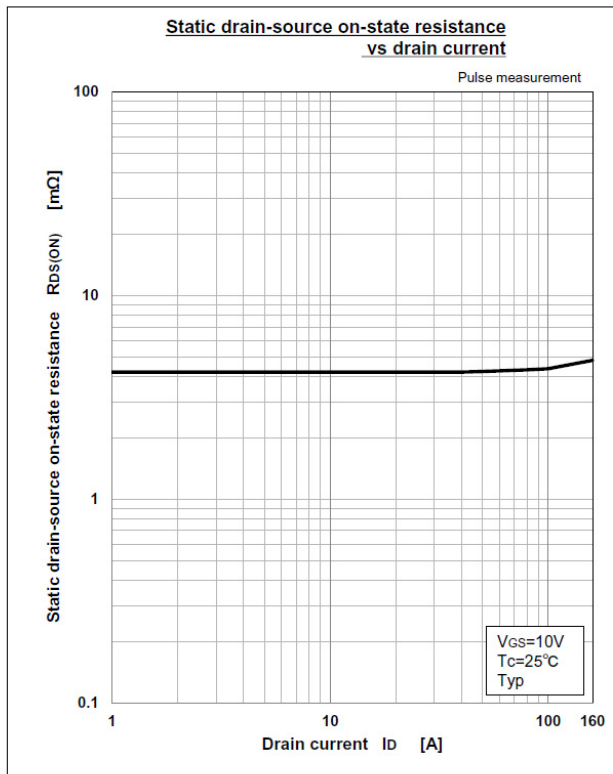
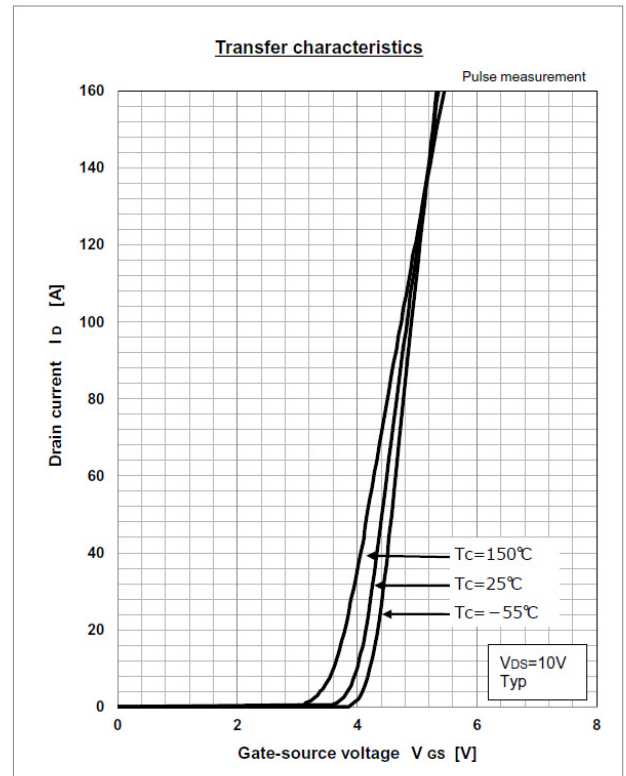
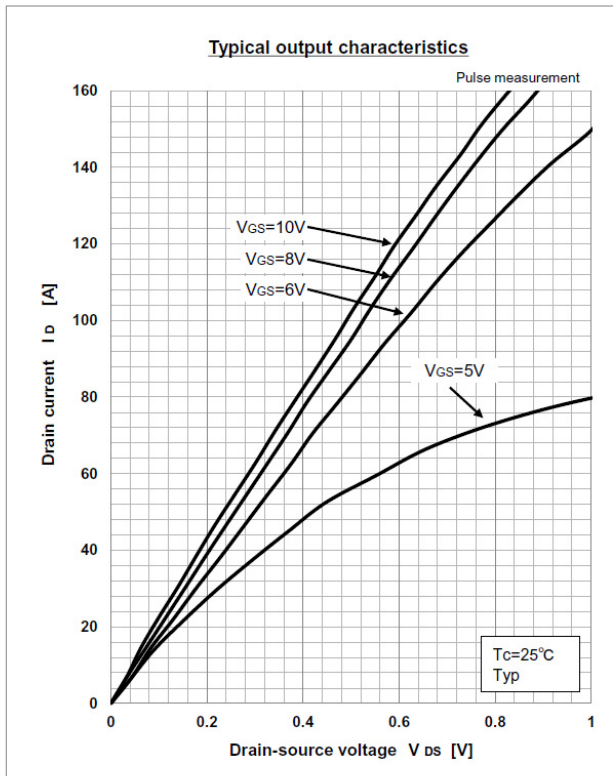
MOSFET

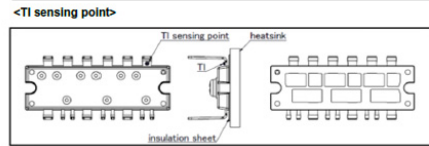
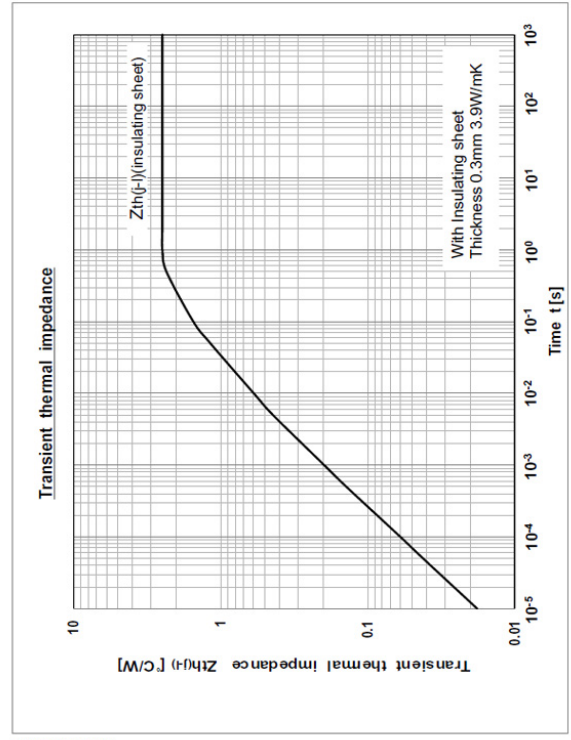
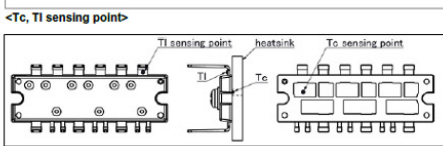
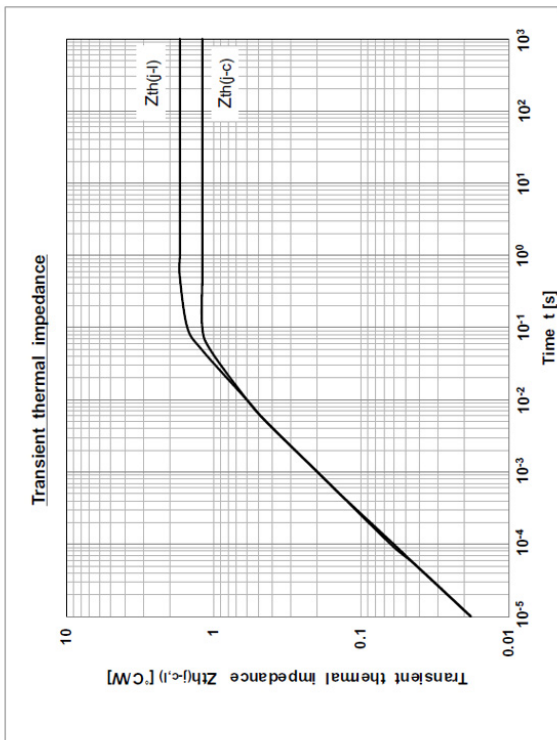
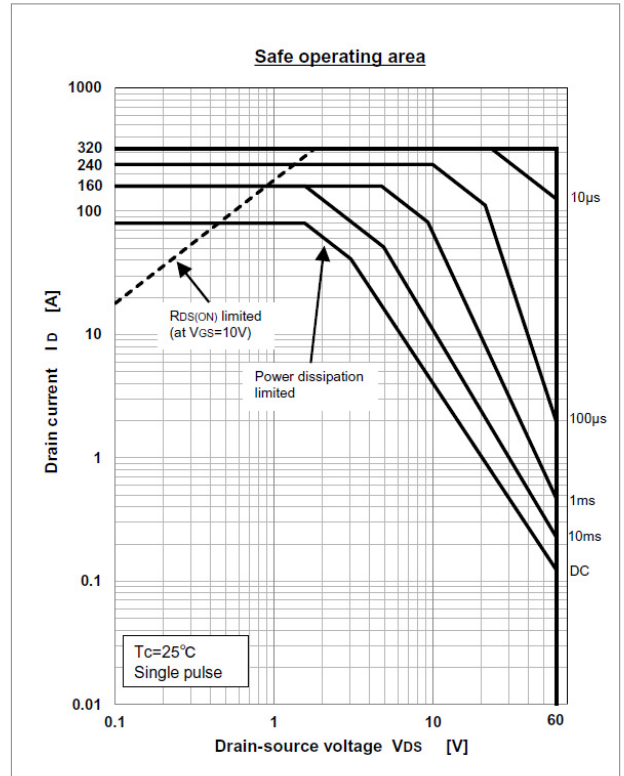
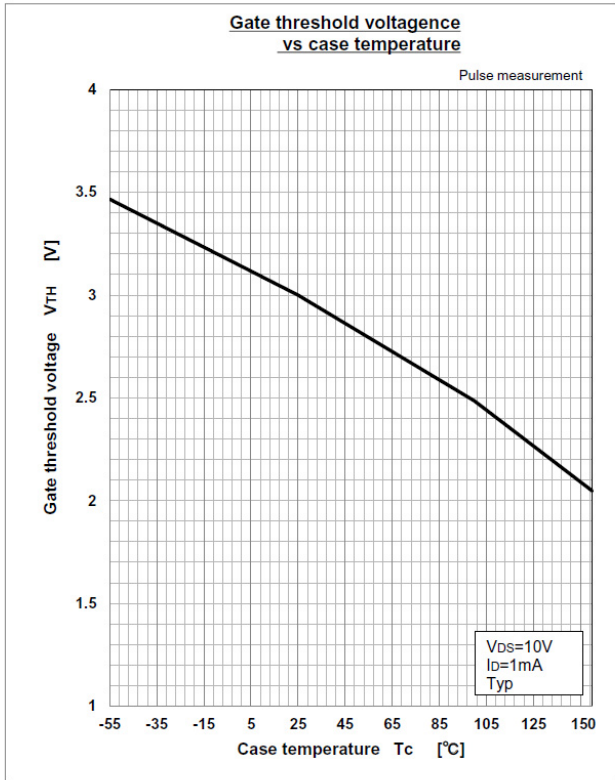
Item	Symbol	Conditions	Ratings			Unit	
			Min.	Typ.	Max.		
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D=1mA, V_{GS}=0V$	60	—	—	V	
Zero gate voltage drain current	I_{DSS}	$V_{DS}=60V, V_{GS}=0V$	—	—	1.0	μA	
Gate-source leakage current	I_{GSS}	$V_{GS}=\pm 20V, V_{DS}=0V$	—	—	± 0.1	μA	
Static drain-source on-state resistance	$R_{DS(ON)}$	Chip	$I_D=40A, V_{GS}=10V$	—	3.74	—	m Ω
		Terminal	$I_D=40A, V_{GS}=10V$	—	4.2	5.6	m Ω
Gate threshold voltage	V_{TH}	$I_D=1mA, V_{DS}=10V$	2.0	3.0	4.0	V	
Source-drain diode forward voltage	V_{SD}	$I_S=80A, V_{GS}=0V$	—	—	1.5	V	
Total gate charge	Qg	$V_{DD}=48V, V_{GS}=10V, I_D=80A$ (Electrical characteristics of discrete MOSFET device)	—	60	—	nC	
Gate to source charge	Qgs		—	17	—		
Gate to drain charge	Qgd		—	18	—		
Input capacitance	Ciss	$V_{DS}=25V, V_{GS}=0V, f=1MHz$ (Electrical characteristics of discrete MOSFET device)	—	3381	—	pF	
Reverse transfer capacitance	Crss		—	164	—		
Output capacitance	Coss		—	380	—		
Turn-on delay time	td(on)	$I_D=40A, V_{DD}=30V, R_L=0.75\Omega, R_g=0\Omega,$ $V_{GS(+)}=10V, V_{GS(-)}=0V$ (Electrical characteristics of discrete MOSFET device)	—	9	—	ns	
Rise time	tr		—	37	—		
Turn-off delay time	td(off)		—	30	—		
Fall time	tf		—	7	—		
Source-drain diode reverse recovery time	trr	$I_F=80A, V_{GS}=0V, di/dt=100A/\mu s$	—	32	—	ns	
Source-drain diode reverse recovery charge	Qrr		—	47	—	nC	

Module

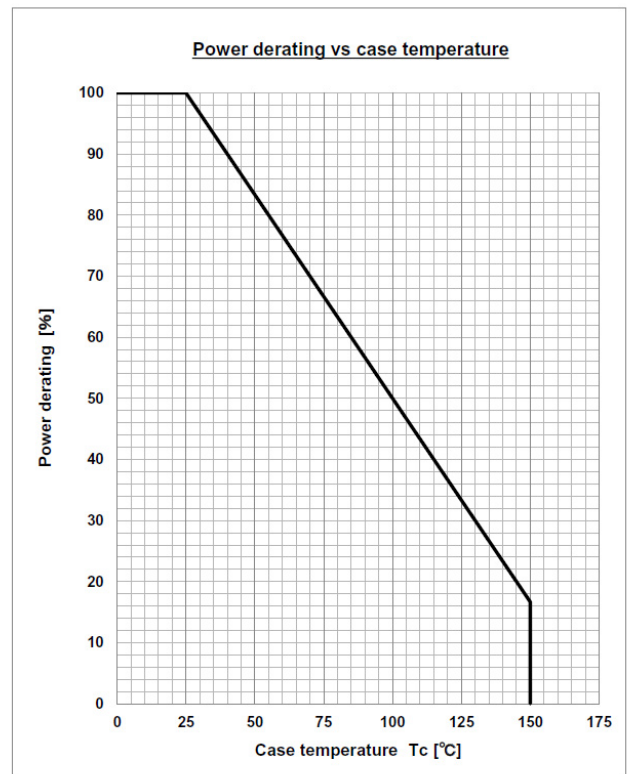
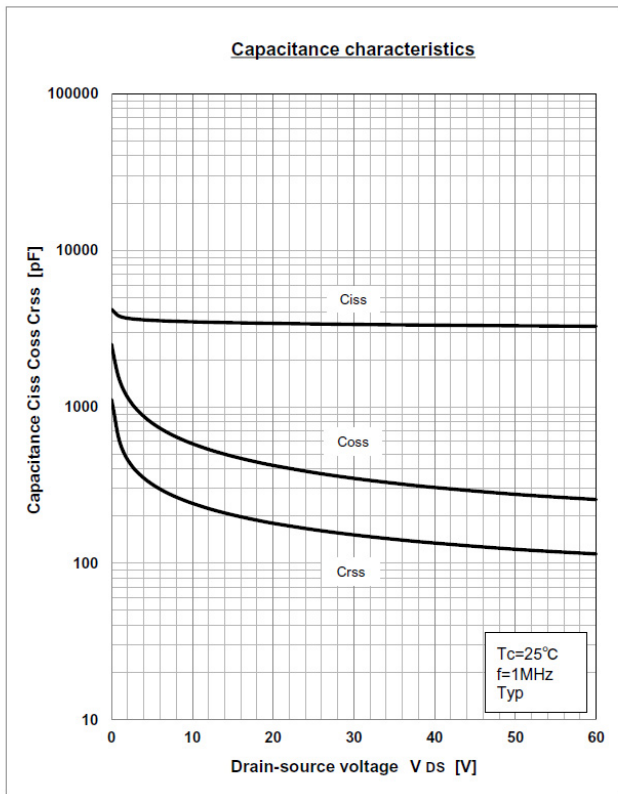
Item	Symbol	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
Thermal resistance	$R_{th(j-c)}$	Junction to case	—	—	1.2	$^{\circ}C/W$
	$R_{th(j-l)}$	Junction to lead	—	—	1.7	
		Junction to lead, With insulating sheet, Thickness 0.3mm, Thermal conductivity 3.9W/mK	—	—	2.5	

CHARACTERISTIC DIAGRAMS

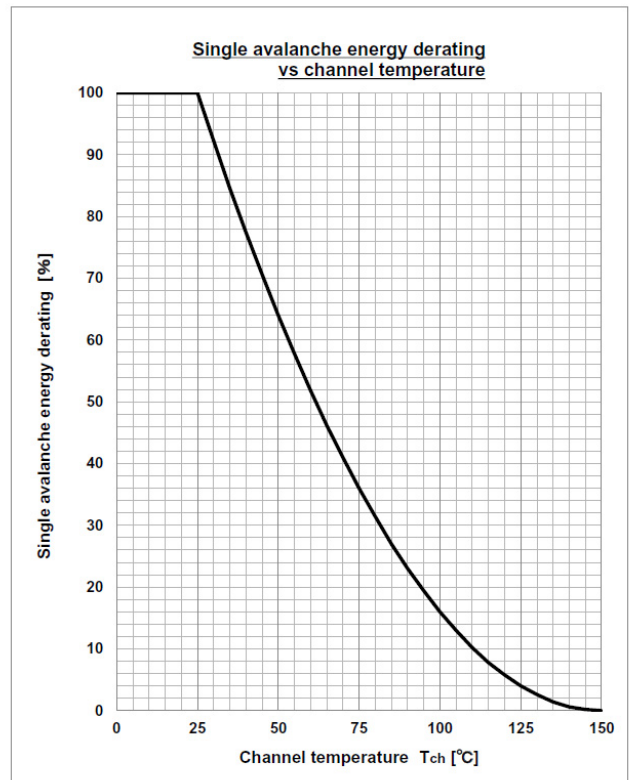
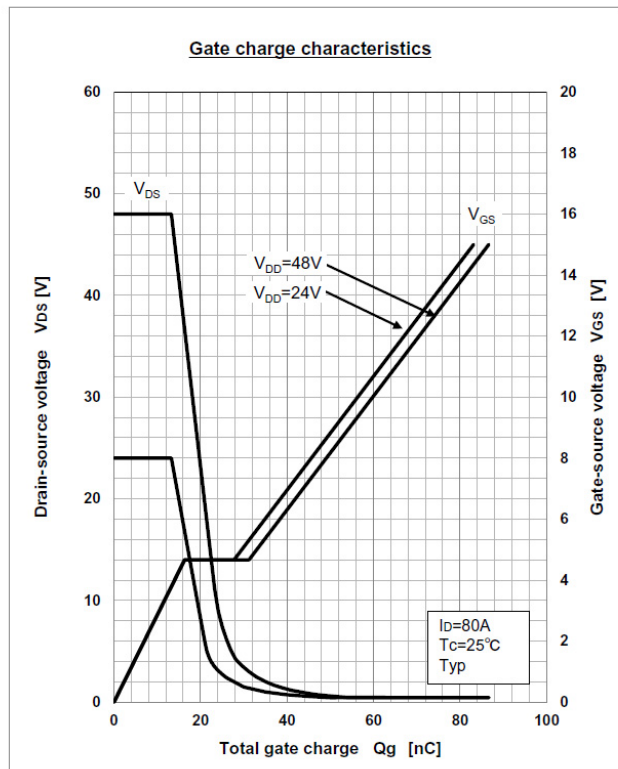




This figure shows the data of a discrete MOSFET device.



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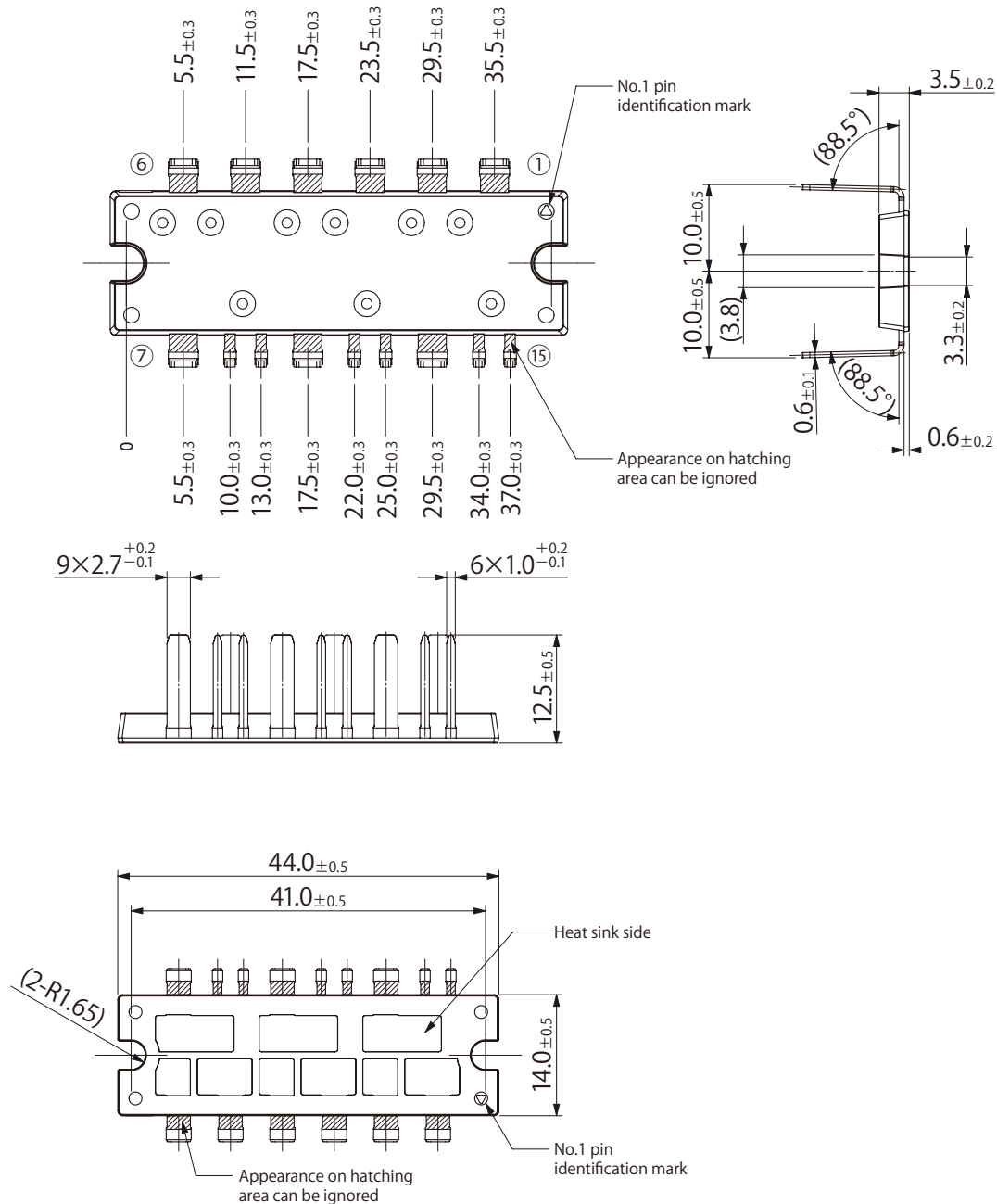


Package Outline-Dimensions

unit : mm

F5

JEDEC Code	-
JEITA Code	-
House Name	MG031



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U182 (2019.12)

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